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Details

Product Status	Active
Core Processor	e200z4d
Core Size	32-Bit Single-Core
Speed	120MHz
Connectivity	CANbus, LINbus, SPI, UART/USART
Peripherals	DMA, POR, PWM, WDT
Number of I/O	147
Program Memory Size	1.5MB (1.5M x 8)
Program Memory Type	FLASH
EEPROM Size	64K x 8
RAM Size	128K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 27x10b, 5x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	176-LQFP
Supplier Device Package	176-LQFP (24x24)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/spc564b64l7b9ecx

Table 1. Device summary

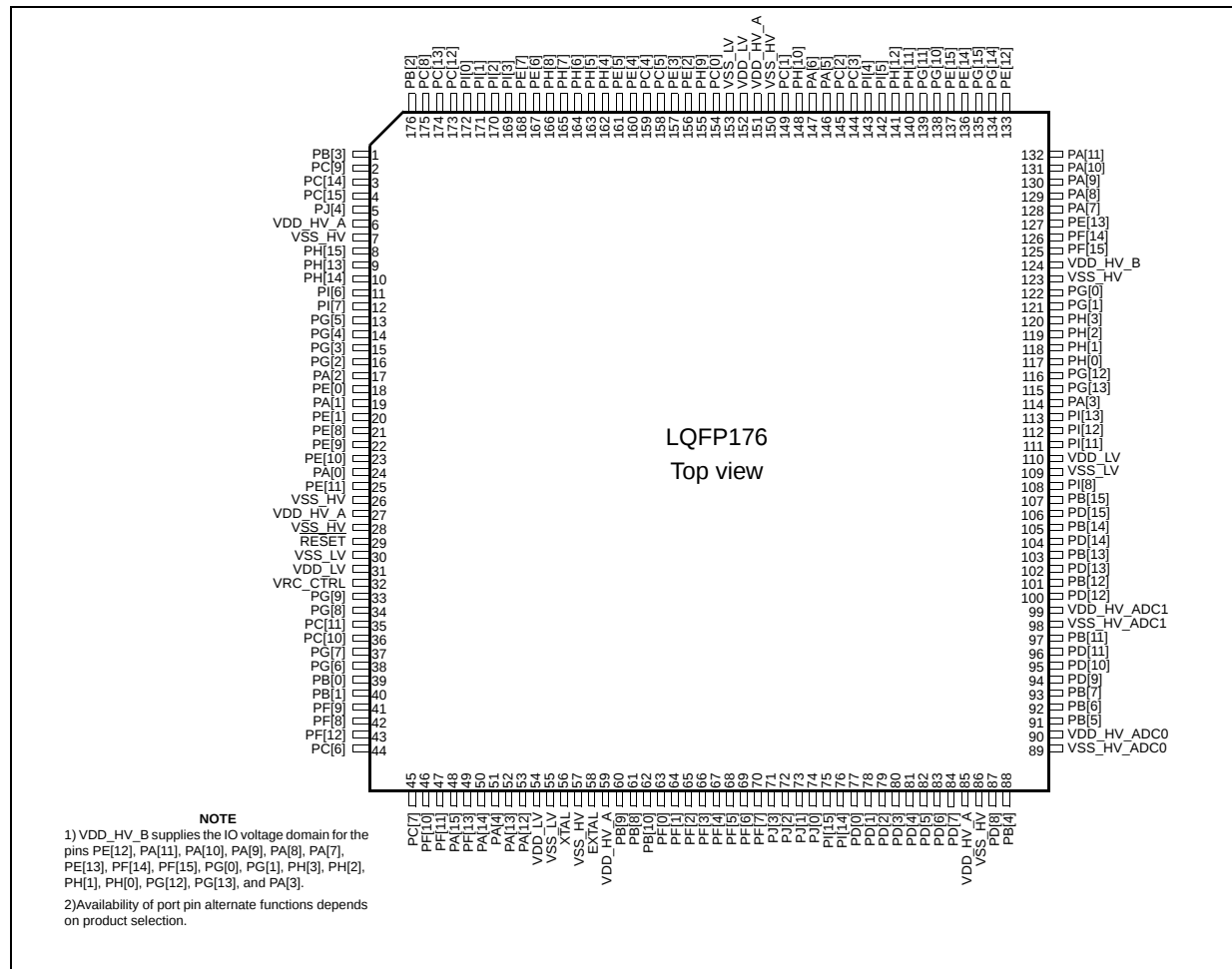
Package	Part number		
	1.5 MByte	2 MByte	3 MByte
LQFP176	SPC564B64L7 SPC56EC64L7	SPC564B70L7 SPC56EC70L7	SPC564B74L7 SPC56EC74L7
LQFP208	SPC564B64L8 SPC56EC64L8	SPC564B70L8 SPC56EC70L8	SPC564B74L8 SPC56EC74L8
LBGA256	SPC56EC64B3	SPC56EC70B3	SPC56EC74B3

Revision history 118

2 Package pinouts and signal descriptions

The available LQFP pinouts and the LBGA ballmaps are provided in the following figures.
For functional port pin description, see [Table 6](#).

Figure 2. 176-pin LQFP configuration



	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	
A	PC[15]	PB[2]	PC[13]	PI[1]	PE[7]	PH[8]	PE[2]	PE[4]	PC[4]	PE[3]	PH[9]	PI[4]	PH[11]	PE[14]	PA[10]	PG[11]	A
B	PH[13]	PC[14]	PC[8]	PC[12]	PI[3]	PE[6]	PH[5]	PE[5]	PC[5]	PC[0]	PC[2]	PH[12]	PG[10]	PA[11]	PA[9]	PA[8]	B
C	PH[14]	VDD_HV_A	PC[9]	PL[0]	PI[0]	PH[7]	PH[6]	VSS_LV	VDD_HV_A	PA[5]	PC[3]	PE[15]	PG[14]	PE[12]	PA[7]	PE[13]	C
D	PG[5]	PI[6]	PJ[4]	PB[3]	PK[15]	PI[2]	PH[4]	VDD_LV	PC[1]	PH[10]	PA[6]	PI[5]	PG[15]	PF[14]	PF[15]	PH[2]	D
E	PG[3]	PI[7]	PH[15]	PG[2]	VDD_LV	VSS_LV	PK[10]	PK[9]	PM[1]	PM[0]	PL[15]	PL[14]	PG[0]	PG[1]	PH[0]	VDD_HV_A	E
F	PA[2]	PG[4]	PA[1]	PE[1]	PL[2]	PM[6]	PL[1]	PK[11]	PM[5]	PL[13]	PL[12]	PM[2]	PH[1]	PH[3]	PG[12]	PG[13]	F
G	PE[8]	PE[0]	PE[10]	PA[0]	PL[3]	VSS_HV	VSS_HV	VSS_HV	VSS_HV	VSS_HV	VSS_HV	PK[12]	VDD_HV_B	PI[13]	PI[12]	PA[3]	G
H	PE[9]	VDD_HV_A	PE[11]	PK[1]	PL[4]	VSS_LV	VSS_LV	VSS_HV	VSS_HV	VSS_HV	VSS_HV	PK[13]	VDD_HV_A	VDD_LV	VSS_LV	PI[11]	H
J	VSS_HV	VRC_CTL	VDD_LV	PG[9]	PL[5]	VSS_LV	VSS_LV	VSS_LV	VSS_HV	VSS_HV	VSS_HV	PK[14]	PD[15]	PI[8]	PI[9]	PI[10]	J
K	RESET	VSS_LV	PG[8]	PC[11]	PL[6]	VSS_LV	VSS_LV	VSS_LV	VSS_LV	VDD_LV	VDD_LV	PM[3]	PD[14]	PD[13]	PB[14]	PB[15]	K
L	PC[10]	PG[7]	PB[0]	PK[2]	PL[7]	VSS_LV	VSS_LV	VSS_LV	VSS_LV	VDD_LV	VDD_LV	PM[4]	PD[12]	PB[12]	PB[13]	VDD_HV_ADC1	L
M	PG[6]	PB[1]	PK[4]	PF[9]	PK[5]	PK[6]	PK[7]	PK[8]	PL[8]	PL[9]	PL[10]	PL[11]	PB[11]	PD[10]	PD[11]	VSS_HV_ADC1	M
N	PK[3]	PF[8]	PC[6]	PC[7]	PJ[13]	VDD_HV_A	PB[10]	PF[6]	VDD_HV_A	PJ[1]	PD[2]	PJ[5]	PB[5]	PB[6]	PJ[6]	PD[9]	N
P	PF[12]	PF[10]	PF[13]	PA[14]	PJ[9]	PA[12]	PF[0]	PF[5]	PF[7]	PJ[3]	PI[15]	PD[4]	PD[7]	PD[8]	PJ[8]	PJ[7]	P
R	PF[11]	PA[15]	PJ[11]	PJ[15]	PA[13]	PF[2]	PF[3]	PF[4]	VDD_LV	PJ[2]	PJ[0]	PD[0]	PD[3]	PD[6]	VDD_HV_ADC0	PB[7]	R
T	PJ[12]	PA[4]	PK[0]	PJ[14]	PJ[10]	PF[1]	XTAL	EXTAL	VSS_LV	PB[9]	PB[8]	PI[14]	PD[1]	PD[5]	VSS_HV_ADC0	PB[4]	T
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	

Notes:

- 1) VDD_HV_B supplies the IO voltage domain for the pins PE[12], PA[11], PA[10], PA[9], PA[8], PA[7], PE[13], PF[14], PF[15], PG[0], PG[1], PH[3], PH[2], PH[1], PH[0], PG[12], PG[13], PA[3], PM[3], and PM[4].
- 2) Availability of port pin alternate functions depends on product selection.

Figure 4. 256-pin BGA configuration

Table 5. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function ⁽¹⁾	Function	Peripheral	I/O direction ⁽²⁾	Pad type	RESET config.	Pin number		
								LQFP 176	LQFP 208	LBGA256
PA[5]	PCR[5]	AF0 AF1 AF2	GPIO[5] E0UC[5] LIN4TX	SIUL eMIOS_0 LINFlexD_4	I/O I/O O	M/S	Tristate	146	170	C10
PA[6]	PCR[6]	AF0 AF1 AF2 AF3 — —	GPIO[6] E0UC[6] — CS1_1 LIN4RX EIRQ[1]	SIUL eMIOS_0 — DSPI_1 LINFlexD_4 SIUL	I/O I/O — O I I	S	Tristate	147	171	D11
PA[7]	PCR[7]	AF0 AF1 AF2 AF3 — — —	GPIO[7] E0UC[7] LIN3TX — RXD[2] EIRQ[2] ADC1_S[1]	SIUL eMIOS_0 LINFlexD_3 — FEC SIUL ADC_1	I/O I/O O — I I I	M/S	Tristate	128	152	C15
PA[8]	PCR[8]	AF0 AF1 AF2 AF3 — — — —	GPIO[8] E0UC[8] E0UC[14] — RXD[1] EIRQ[3] ABS[0] LIN3RX	SIUL eMIOS_0 eMIOS_0 — FEC SIUL MC_RGM LINFlexD_3	I/O I/O I/O — I I I I	M/S	Input, weak pull-up	129	153	B16
PA[9]	PCR[9]	AF0 AF1 AF2 AF3 — —	GPIO[9] E0UC[9] — CS2_1 RXD[0] FAB	SIUL eMIOS_0 — DSPI1 FEC MC_RGM	I/O I/O — O I I	M/S	Pull-down	130	154	B15

Table 5. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function ⁽¹⁾	Function	Peripheral	I/O direction ⁽²⁾	Pad type	RESET config.	Pin number		
								LQFP 176	LQFP 208	LBGA256
PB[0]	PCR[16]	AF0 AF1 AF2 AF3	GPIO[16] CAN0TX E0UC[30] LIN0TX	SIUL FlexCAN_0 eMIOS_0 LINFlexD_0	I/O O I/O I	M/S	Tristate	39	39	L3
PB[1]	PCR[17]	AF0 AF1 AF2 — — —	GPIO[17] — E0UC[31] LIN0RX WKPU[4] CAN0RX	SIUL — eMIOS_0 LINFlexD_0 WKPU FlexCAN_0	I/O — I/O I I I	S	Tristate	40	40	M2
PB[2]	PCR[18]	AF0 AF1 AF2 AF3	GPIO[18] LIN0TX SDA E0UC[30]	SIUL LINFlexD_0 I ² C eMIOS_0	I/O O I/O I/O	M/S	Tristate	176	208	A2
PB[3]	PCR[19]	AF0 AF1 AF2 AF3 — —	GPIO[19] E0UC[31] SCL — WKPU[11] LIN0RX	SIUL eMIOS_0 I ² C — WKPU LINFlexD_0	I/O I/O I/O — I I	S	Tristate	1	1	D4
PB[4]	PCR[20]	AF0 AF1 AF2 AF3 — —	GPI[20] — — — ADC0_P[0] ADC1_P[0]	SIUL — — — ADC_0 ADC_1	I — — — I I	I	Tristate	88	104	T16
PB[5]	PCR[21]	AF0 AF1 AF2 AF3 — —	GPI[21] — — — ADC0_P[1] ADC1_P[1]	SIUL — — — ADC_0 ADC_1	I — — — I I	I	Tristate	91	107	N13

Table 5. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function ⁽¹⁾	Function	Peripheral	I/O direction ⁽²⁾	Pad type	RESET config.	Pin number		
								LQFP 176	LQFP 208	LBGA256
PI[7]	PCR[135]	AF0 AF1 AF2 AF3 ALT4	GPIO[135] E1UC[31] CS1_4 CS1_5 CS1_6	SIUL eMIOS_1 DSPI_4 DSPI_5 DSPI_6	I/O I/O O O O	S	Tristate	12	12	E2
PI[8]	PCR[136]	AF0 AF1 AF2 AF3 —	GPIO[136] — — — ADC0_S[16]	SIUL — — — ADC_0	I/O — — — I	S	Tristate	108	130	J14
PI[9]	PCR[137]	AF0 AF1 AF2 AF3 —	GPIO[137] — — — ADC0_S[17]	SIUL — — — ADC_0	I/O — — — I	S	Tristate	—	131	J15
PI[10]	PCR[138]	AF0 AF1 AF2 AF3 —	GPIO[138] — — — ADC0_S[18]	SIUL — — — ADC_0	I/O — — — I	S	Tristate	—	134	J16
PI[11]	PCR[139]	AF0 AF1 AF2 AF3 — —	GPIO[139] — — — ADC0_S[19] SIN_3	SIUL — — — ADC_0 DSPI_3	I/O — — — I I	S	Tristate	111	135	H16
PI[12]	PCR[140]	AF0 AF1 AF2 AF3 —	GPIO[140] CS0_3 CS0_2 — ADC0_S[20]	SIUL DSPI_3 DSPI_2 — ADC_0	I/O I/O I/O — I	S	Tristate	112	136	G15

Table 5. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function ⁽¹⁾	Function	Peripheral	I/O direction ⁽²⁾	Pad type	RESET config.	Pin number		
								LQFP 176	LQFP 208	LBGA256
PJ[10]	PCR[154]	AF0	GPIO[154]	SIUL	I/O	S	Tristate	—	67	T5
		AF1	—	—	—					
		AF2	—	—	—					
		AF3	—	—	—					
		—	ADC1_S[9]	ADC_1	I					
PJ[11]	PCR[155]	AF0	GPIO[155]	SIUL	I/O	S	Tristate	—	60	R3
		AF1	—	—	—					
		AF2	—	—	—					
		AF3	—	—	—					
		—	ADC1_S[10]	ADC_1	I					
PJ[12]	PCR[156]	AF0	GPIO[156]	SIUL	I/O	S	Tristate	—	59	T1
		AF1	—	—	—					
		AF2	—	—	—					
		AF3	—	—	—					
		—	ADC1_S[11]	ADC_1	I					
PJ[13]	PCR[157]	AF0	GPIO[157]	SIUL	I/O	S	Tristate	—	65	N5
		AF1	—	—	—					
		AF2	CS1_7	DSPI_7	O					
		AF3	—	—	—					
		—	CAN4RX	FlexCAN_4	I					
		—	ADC1_S[12]	ADC_1	I					
		—	CAN1RX	FlexCAN_1	I					
PJ[14]	PCR[158]	AF0	GPIO[158]	SIUL	I/O	M/S	Tristate	—	64	T4
		AF1	CAN1TX	FlexCAN_1	O					
		AF2	CAN4TX	FlexCAN_4	O					
		AF3	CS2_7	DSPI_7	O					
		—	—	—	—					
PJ[15]	PCR[159]	AF0	GPIO[159]	SIUL	I/O	M/S	Tristate	—	63	R4
		AF1	—	—	—					
		AF2	CS1_6	DSPI_6	O					
		AF3	—	—	—					
		—	CAN1RX	FlexCAN_1	I					

3.5.2 Power considerations

The average chip-junction temperature, T_J , in degrees Celsius, may be calculated using [Equation 1](#):

$$\text{Equation 1 } T_J = T_A + (P_D \times R_{\theta JA})$$

Where:

T_A is the ambient temperature in °C.

$R_{\theta JA}$ is the package junction-to-ambient thermal resistance, in °C/W.

P_D is the sum of P_{INT} and $P_{I/O}$ ($P_D = P_{INT} + P_{I/O}$).

P_{INT} is the product of I_{DD} and V_{DD} , expressed in watts. This is the chip internal power.

$P_{I/O}$ represents the power dissipation on input and output pins; user determined.

Most of the time for the applications, $P_{I/O} < P_{INT}$ and may be neglected. On the other hand, $P_{I/O}$ may be significant, if the device is configured to continuously drive external modules and/or memories.

An approximate relationship between P_D and T_J (if $P_{I/O}$ is neglected) is given by:

$$\text{Equation 2 } P_D = K / (T_J + 273 \text{ °C})$$

Therefore, solving equations [Equation 1](#) and [Equation 2](#):

$$\text{Equation 3 } K = P_D \times (T_A + 273 \text{ °C}) + R_{\theta JA} \times P_D^2$$

Where:

K is a constant for the particular part, which may be determined from [Equation 3](#) by measuring P_D (at equilibrium) for a known T_A . Using this value of K , the values of P_D and T_J may be obtained by solving equations [Equation 1](#) and [Equation 2](#) iteratively for any value of T_A .

3.6 I/O pad electrical characteristics

3.6.1 I/O pad types

The device provides four main I/O pad types depending on the associated alternate functions:

- Slow pads—These pads are the most common pads, providing a good compromise between transition time and low electromagnetic emission.
- Medium pads—These pads provide transition fast enough for the serial communication channels with controlled current to reduce electromagnetic emission.
- Fast pads—These pads provide maximum speed. These are used for improved Nexus debugging capability.
- Input only pads—These pads are associated to ADC channels and 32 kHz low power external crystal oscillator providing low input leakage.
- Low power pads—These pads are active in standby mode for wakeup source.

Also, medium/slow and fast/medium pads are available in design which can be configured to behave like a slow/medium and medium/fast pads depending upon the slew-rate control.

Table 16. SLOW configuration output buffer electrical characteristics (continued)

Symbol	C	Parameter	Conditions ^{(1),(2)}	Value			Unit
				Min	Typ	Max	
V _{OL}	CC	P	Push Pull Output low level SLOW configuration	I _{OL} = 3 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	0.1V _{DD}
		C		I _{OL} = 3 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 1 ⁽³⁾	—	—	0.1V _{DD}
		P		I _{OL} = 1.5 mA, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	0.5

1. V_{DD} = 3.3 V ± 10 % / 5.0 V ± 10 %, T_A = -40 to 125 °C, unless otherwise specified.
2. V_{DD} as mentioned in the table is V_{DD_HV_A}/V_{DD_HV_B}.
3. The configuration PAD3V5 = 1 when V_{DD} = 5 V is only a transient configuration during power-up. All pads but RESET and Nexus output (MDOx, EVTO, MCKO) are configured in input or in high impedance state.

Table 17. MEDIUM configuration output buffer electrical characteristics

Symbol	C	Parameter	Conditions ^{(1),(2)}	Value			Unit
				Min	Typ	Max	
V _{OH}	CC	C	Push Pull Output high level MEDIUM configuration	I _{OH} = -3 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	0.8V _{DD}	—	—
		C		I _{OH} = -1.5 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 1 ⁽³⁾	0.8V _{DD}	—	—
		C		I _{OH} = -2 mA, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	V _{DD} - 0.8	—	—
V _{OL}	CC	C	Push Pull Output low level MEDIUM configuration	I _{OL} = 3 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	0.2V _{DD}
		C		I _{OL} = 1.5 mA, V _{DD} = 5.0 V ± 10%, PAD3V5V = 1 ⁽³⁾	—	—	0.1V _{DD}
		C		I _{OL} = 2 mA, V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	0.5

1. V_{DD} = 3.3 V ± 10 % / 5.0 V ± 10 %, T_A = -40 to 125 °C, unless otherwise specified.
2. V_{DD} as mentioned in the table is V_{DD_HV_A}/V_{DD_HV_B}.
3. The configuration PAD3V5 = 1 when V_{DD} = 5 V is only a transient configuration during power-up. All pads but RESET and Nexus output (MDOx, EVTO, MCKO) are configured in input or in high impedance state.

Table 23. Voltage regulator electrical characteristics (continued)

Symbol		C	Parameter	Conditions ⁽¹⁾	Value ⁽²⁾			Unit
					Min	Typ	Max	
I _{MREG}	S R	—	Main regulator current provided to V _{DD_LV} domain	—	—	350	mA	
I _{MREGINT}	C C	D	Main regulator module current consumption	I _{MREG} = 200 mA	—	—	2	mA
				I _{MREG} = 0 mA	—	—	1	
V _{LPREG}	C C	P	Low power regulator output voltage	After trimming T _A = 25 °C	1.17	1.27	1.32	V
I _{LPREG}	S R	—	Low power regulator current provided to V _{DD_LV} domain	—	—	50	mA	
I _{LPREGINT}	C C	D	Low power regulator module current consumption	I _{LPREG} = 15 mA; T _A = 55 °C	—	—	600	μA
		—		I _{LPREG} = 0 mA; T _A = 55 °C	—	20	—	
I _{VREGREF}	C C	D	Main LVDs and reference current consumption (low power and main regulator switched off)	T _A = 55 °C	—	2	—	μA
I _{VREDLVD12}	C C	D	Main LVD current consumption (switch-off during standby)	T _A = 55 °C	—	1	—	μA
I _{DD_HV_A}	C C	D	In-rush current on V _{DD_BV} during power-up	—	—	—	600 (3)	mA

1. $V_{DD_HV_A} = 3.3$ V $\pm$ 10 % / 5.0 V $\pm$ 10 %, $T_A = -40$ to 125 °C, unless otherwise specified.

2. All values need to be confirmed during device validation.

3. Inrush current is seen more like steps of 600 mA peak. The startup of the regulator happens in steps of 50 mV in ~25 steps to reach ~1.2 V V_{DD_LV} . Each step peak current is within 600 mA

3.8.3 Voltage monitor electrical characteristics

The device implements a Power-on Reset module to ensure correct power-up initialization, as well as four low voltage detectors to monitor the $V_{DD_HV_A}$ and the V_{DD_LV} voltage while device is supplied:

- POR monitors $V_{DD_HV_A}$ during the power-up phase to ensure device is maintained in a safe reset state
- LVDHV3 monitors $V_{DD_HV_A}$ to ensure device is reset below minimum functional supply
- LVDHV5 monitors $V_{DD_HV_A}$ when application uses device in the 5.0 V $\pm$ 10 % range
- LVDLVCOR monitors power domain No. 1 (PD1)
- LVDLVBKP monitors power domain No. 0 (PD0). V_{DD_LV} is same as PD0 supply.

Note: When enabled, PD2 (RAM retention) is monitored through LVD_DIGBKP.

3.17.1.2 ADC electrical characteristics

Table 42. ADC input leakage current

Symbol	C	Parameter	Conditions	Value			Unit
				Min	Typ	Max	
I _{LKG}	CC	Input leakage current	T _A = -40 °C	—	1	—	nA
			T _A = 25 °C	—	1	—	
			T _A = 105 °C	—	8	200	
			T _A = 125 °C	—	45	400	

Table 43. ADC conversion characteristics (10-bit ADC_0)

Symbol	C	Parameter	Conditions ⁽¹⁾	Value			Unit
				Min	Typ	Max	
V _{SS_ADC0}	S R	—	Voltage on VSS_HV_ADC0 (ADC_0 reference) pin with respect to ground (V _{SS_HV}) ⁽²⁾	—	—	0.1	V
V _{DD_ADC0}	S R	—	Voltage on VDD_HV_ADC0 pin (ADC_0 reference) with respect to ground (V _{SS_HV})	—	V _{DD_HV_A} - 0.1	V _{DD_HV_A} + 0.1	V
V _{AINx}	S R	—	Analog input voltage ⁽³⁾	—	V _{SS_ADC0} - 0.1	V _{DD_ADC0} + 0.1	V
f _{ADC0}	S R	—	ADC_0 analog frequency	—	6	32 + 2%	MHz
t _{ADC0_PU}	S R	—	ADC_0 power up delay	—	—	1.5	μs
t _{ADC0_S}	C C	T	Sample time ⁽⁴⁾	f _{ADC} = 32 MHz	500	—	ns
t _{ADC0_C}	C C	P	Conversion time ^{(5),(6)}	f _{ADC} = 32 MHz	0.625	—	μs
				f _{ADC} = 30 MHz	0.700	—	
C _S	C C	D	ADC_0 input sampling capacitance	—	—	3	pF
C _{P1}	C C	D	ADC_0 input pin capacitance 1	—	—	3	pF
C _{P2}	C C	D	ADC_0 input pin capacitance 2	—	—	1	pF
C _{P3}	C C	D	ADC_0 input pin capacitance 3	—	—	1	pF
R _{SW1}	C C	D	Internal resistance of analog source	—	—	3	kΩ

Table 43. ADC conversion characteristics (10-bit ADC_0) (continued)

Symbol		C	Parameter	Conditions ⁽¹⁾		Value			Unit
						Min	Typ	Max	
R _{SW2}	C	D	Internal resistance of analog source	—		—	—	2	kΩ
R _{AD}	C	D	Internal resistance of analog source	—		—	—	2	kΩ
I _{INJ} ⁽⁷⁾	S	R	Input current Injection	Current injection on one ADC_0 input, different from the converted one	V _{DD} = 3.3 V ± 10%	–5	—	5	mA
					V _{DD} = 5.0 V ± 10%	–5	—	5	
INL	C	T	Absolute value for integral non-linearity	No overload		—	0.5	1.5	LSB
DNL	C	T	Absolute differential non-linearity	No overload		—	0.5	1.0	LSB
OFS	C	T	Absolute offset error	—		—	0.5	—	LSB
GNE	C	T	Absolute gain error	—		—	0.6	—	LSB
TUEP	C	P	Total unadjusted error ⁽⁸⁾ for precise channels, input only pins	Without current injection		–2	0.6	2	LSB
		T		With current injection		–3		3	
TUEX	C	T	Total unadjusted error ⁽⁸⁾ for extended channel	Without current injection		–3	1	3	LSB
		T		With current injection		–4		4	

1. V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 125 °C, unless otherwise specified.

2. Analog and digital V_{SS_HV} must be common (to be tied together externally).

3. V_{AINx} may exceed V_{SS_ADC0} and V_{DD_ADC0} limits, remaining on absolute maximum ratings, but the results of the conversion will be clamped respectively to 0x000 or 0x3FF.

4. During the sample time the input capacitance C_S can be charged/discharged by the external source. The internal resistance of the analog source must allow the capacitance to reach its final voltage level within t_{ADC0_S}. After the end of the sample time t_{ADC0_S}, changes of the analog input voltage have no effect on the conversion result. Values for the sample clock t_{ADC0_S} depend on programming.

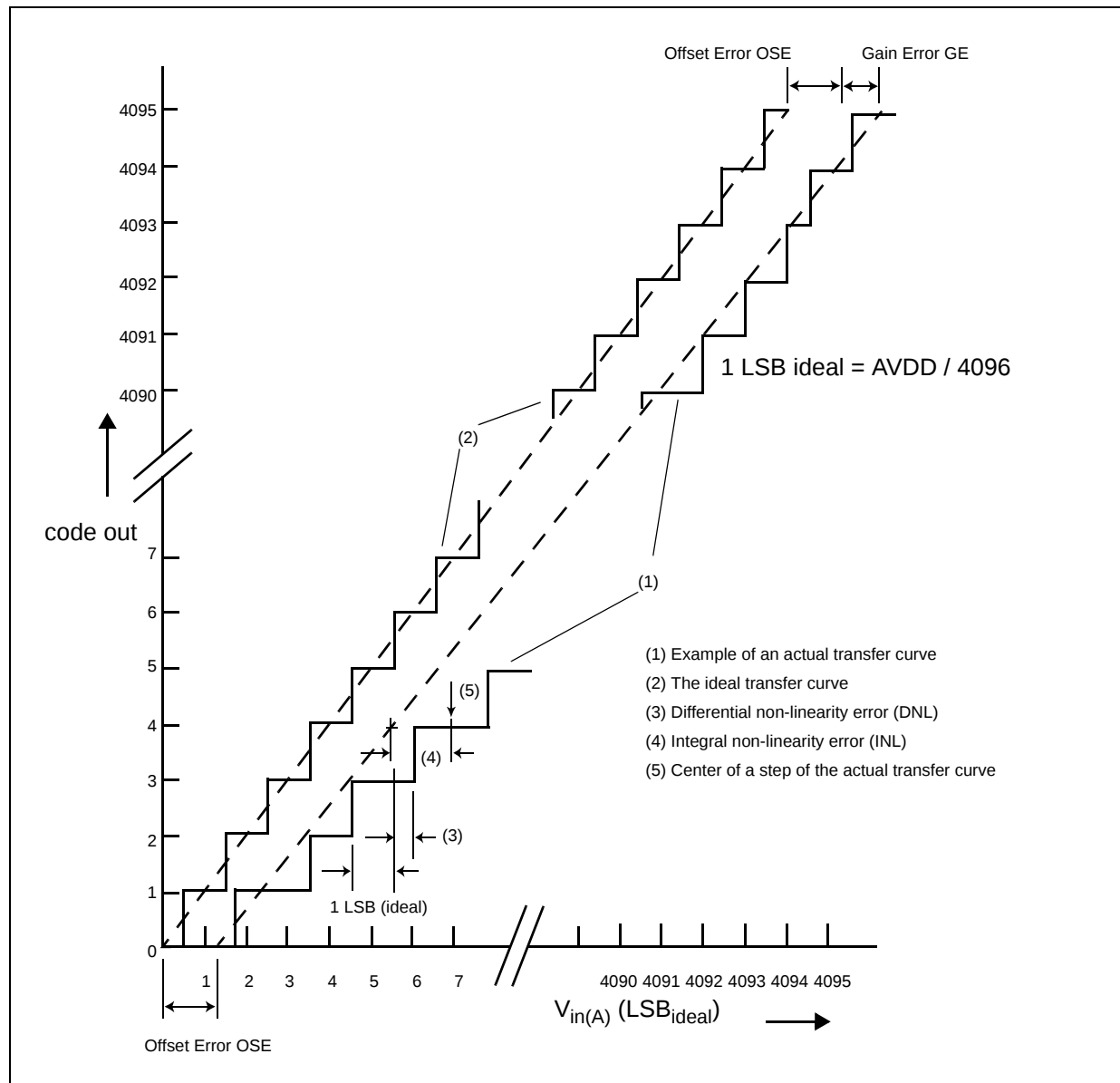
5. This parameter does not include the sample time t_{ADC0_S}, but only the time for determining the digital result and the time to load the result's register with the conversion result.

6. Refer to ADC conversion table for detailed calculations.

7. PB10 should not have any current injected. It can disturb accuracy on other ADC_0 pins.

8. Total Unadjusted Error: The maximum error that occurs without adjusting Offset and Gain errors. This error is a combination of Offset, Gain and Integral Linearity errors.

Figure 20. ADC_1 characteristic and error definitions



- PA3, PA7, PA10, PA11 and PE12 ADC_1 channels are coming from $V_{DD_HV_B}$ domain hence $V_{DD_HV_ADC1}$ should be within ± 100 mV of $V_{DD_HV_B}$ when these channels are used for ADC_1.
- $V_{DD_HV_ADC1}$ can operate at 5V condition while $V_{DD_HV_B}$ can operate at 3.3V provided that ADC_1 channels coming from $V_{DD_HV_B}$ domain are limited in max swing as $V_{DD_HV_B}$.
- V_{AINx} may exceed V_{SS_ADC1} and V_{DD_ADC1} limits, remaining on absolute maximum ratings, but the results of the conversion will be clamped respectively to 0x000 or 0xFFFF.
- During the sample time the input capacitance C_S can be charged/discharged by the external source. The internal resistance of the analog source must allow the capacitance to reach its final voltage level within t_{ADC1_S} . After the end of the sample time t_{ADC1_S} , changes of the analog input voltage have no effect on the conversion result. Values for the sample clock t_{ADC1_S} depend on programming.
- Conversion time = Bit evaluation time + Sampling time + 1 Clock cycle delay.
- Refer to ADC conversion table for detailed calculations.
- Total Unadjusted Error: The maximum error that occurs without adjusting Offset and Gain errors. This error is a combination of Offset, Gain and Integral Linearity errors.

3.18 Fast Ethernet Controller

MII signals use CMOS signal levels compatible with devices operating at 3.3 V. Signals are not TTL compatible. They follow the CMOS electrical characteristics.

3.18.1 MII Receive Signal Timing (RXD[3:0], RX_DV, RX_ER, and RX_CLK)

The receiver functions correctly up to a RX_CLK maximum frequency of 25 MHz +1%. There is no minimum frequency requirement. In addition, the system clock frequency must exceed four times the RX_CLK frequency in 2:1 mode and two times the RX_CLK frequency in 1:1 mode.

Table 45. MII Receive Signal Timing

Spec	Characteristic	Min	Max	Unit
M1	RXD[3:0], RX_DV, RX_ER to RX_CLK setup	5	—	ns
M2	RX_CLK to RXD[3:0], RX_DV, RX_ER hold	5	—	ns
M3	RX_CLK pulse width high	35%	65%	RX_CLK period
M4	RX_CLK pulse width low	35%	65%	RX_CLK period

Figure 21. MII receive signal timing diagram

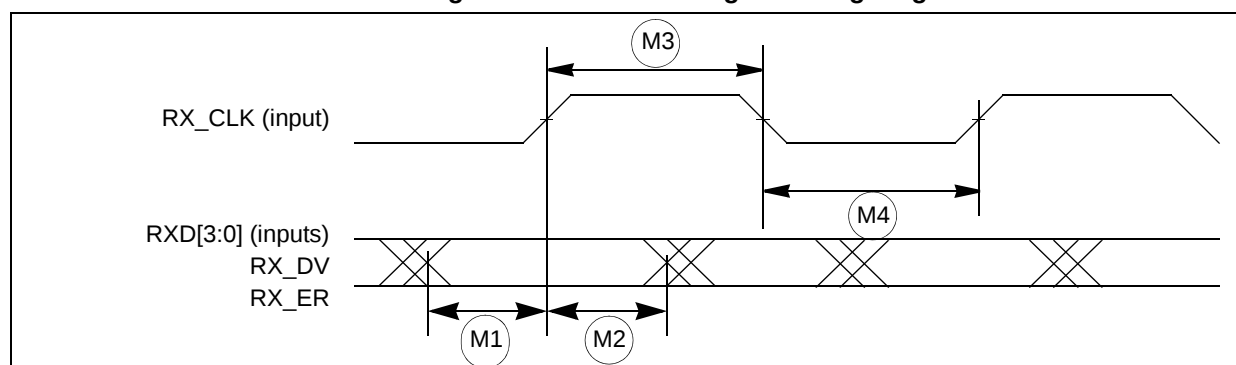


Figure 27. DSPI classic SPI timing–slave, CPHA = 0

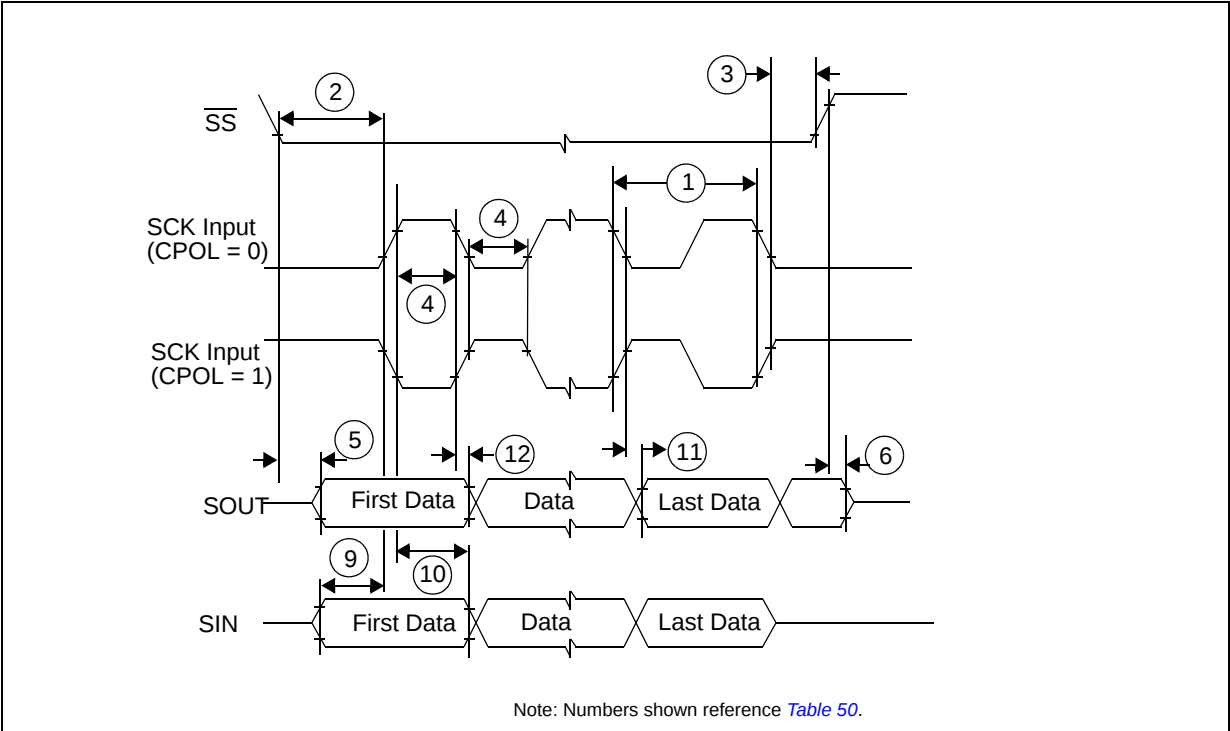


Figure 28. DSPI classic SPI timing–slave, CPHA = 1

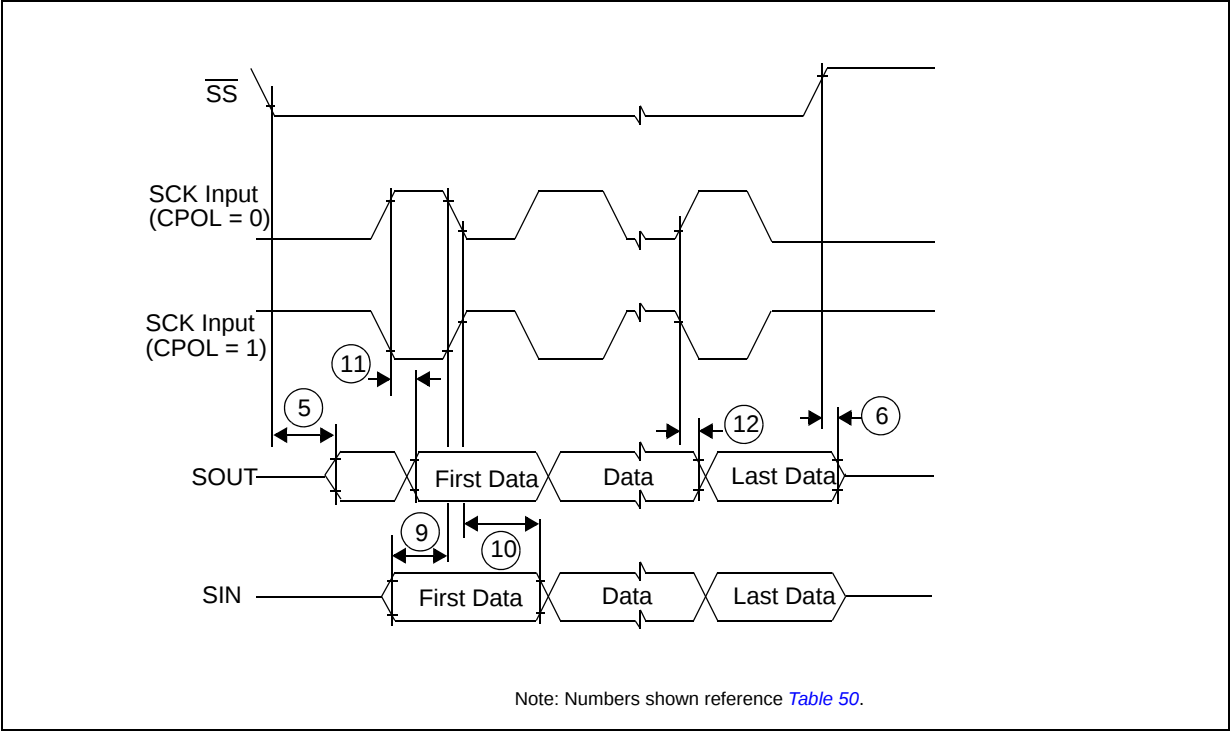
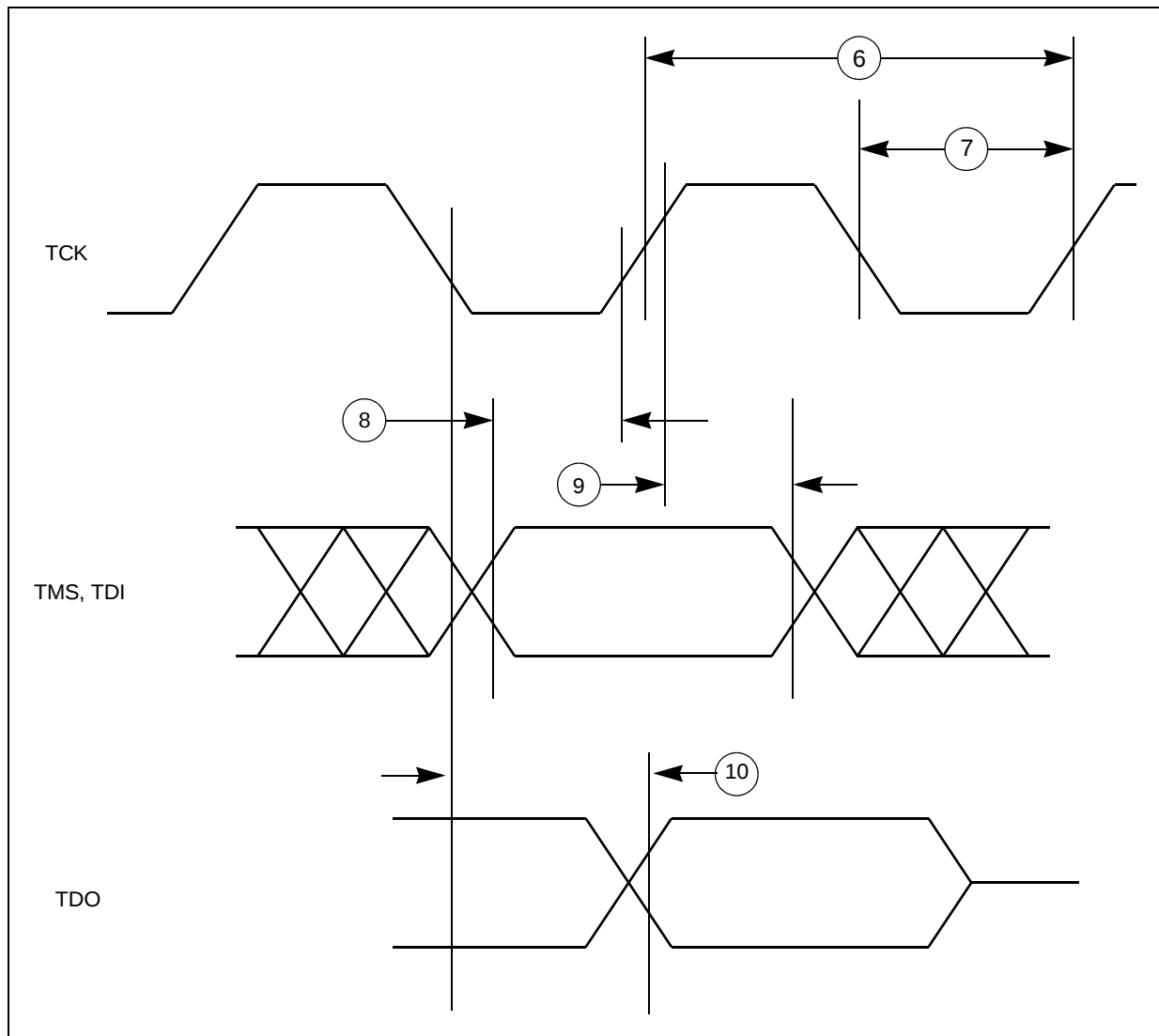


Figure 35. Nexus TDI, TMS, TDO timing



3.19.4 JTAG characteristics

Table 52. JTAG characteristics

No.	Symbol	C	D	Parameter	Value			Unit
					Min	Typ	Max	
1	t_{JCYC}	CC	D	TCK cycle time	64	—	—	ns
2	t_{TDIS}	CC	D	TDI setup time	10	—	—	ns
3	t_{TDIH}	CC	D	TDI hold time	5	—	—	ns
4	t_{TMSS}	CC	D	TMS setup time	10	—	—	ns
5	t_{TMSH}	CC	D	TMS hold time	5	—	—	ns
6	t_{TDOV}	CC	D	TCK low to TDO valid	—	—	33	ns

Table 53. LQFP176 mechanical data⁽¹⁾

Symbol	mm			inches ⁽²⁾		
	Min	Typ	Max	Min	Typ	Max
A	1.400		1.600			0.063
A1	0.050		0.150	0.002		
A2	1.350		1.450	0.053		0.057
b	0.170		0.270	0.007		0.011
C	0.090		0.200	0.004		0.008
D	23.900		24.100	0.941		0.949
E	23.900		24.100	0.941		0.949
e		0.500			0.020	
HD	25.900		26.100	1.020		1.028
HE	25.900		26.100	1.020		1.028
L ⁽³⁾	0.450		0.750	0.018		0.030
L1		1.000			0.039	
ZD		1.250			0.049	
ZE		1.250			0.049	
q	0 °		7 °	0 °		7 °
Tolerance	mm			inches		
ccc	0.080			0.0031		

1. Controlling dimension: millimeter.

2. Values in inches are converted from mm and rounded to 4 decimal digits.

3. L dimension is measured at gauge plane at 0.25 mm above the seating plane.

Table 54. LQFP208 mechanical data

Ref	mm			mm		
	Min	Typ	Max	Min	Typ	Max
A			1.6			1.6
A1	0.05		0.15	0.05	0.1	0.15
A2	1.3	1.35	1.45	1.3	1.35	1.45
B	0.17		0.27	0.17	0.22	0.27
c	0.09		0.2	0.11	0.15	0.19
D		30		29.8	30	30.2
D1		28		27.8	28	28.2
D3		25.5			25.5	
e		0.5			0.5	
E		30		29.8	30	30.2
E1		28		27.8	28	28.2
E3		25.5			25.5	
L	0.45	0.6	0.75	0.4	0.5	0.6
L1		1		1		
K	0 °	3.5 °	7.0 °	1 °	3 °	5 °

Appendix A Abbreviations

[Table 56](#) lists abbreviations used but not defined elsewhere in this document.

Table 56. Abbreviations

Abbreviation	Meaning
CS	Chip select
EVTO	Event out
MCKO	Message clock out
MDO	Message data out
MSEO	Message start/end out
MTFE	Modified timing format enable
SCK	Serial communications clock
SOUT	Serial data out
TBD	To be defined
TCK	Test clock input
TDI	Test data input
TDO	Test data output
TMS	Test mode select